



PS2702-1

Data Sheet

R08DS0099EJ0300 Rev.3.00 Jan 29, 2013

HIGH ISOLATION VOLTAGE DARLINGTON TRANSISTOR SOP MULTI PHOTOCOUPLER SERIES

DESCRIPTION

The PS2702-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon darlington-connected phototransistor.

This is mounted in a plastic SOP (Small Out-line Package) for high density applications.

This package has shield effect to cut off ambient light.

FEATURES

- High current transfer ratio (CTR = 2 000% TYP.)
- High isolation voltage (BV = 3 750 Vr.m.s.)
- Small and thin (SOP) package
- High-speed switching ($t_r = 70 \mu s$ TYP., $t_f = 60 \mu s$ TYP.)
- Ordering number of taping product: PS2702-1-F3

<R> • Safety standards

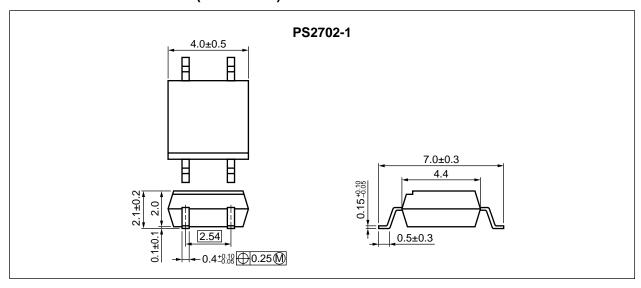
- UL approved: No. E72422
- BSI approved (BS EN 60065, BS EN 60950)
- CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
- DIN EN 60747-5-5 (VDE 0884-5) approved (Option)

PIN CONNECTION (Top View) 1. Anode 2. Cathode 3. Emitter 4. Collector

APPLICATIONS

- Hybrid IC
- Telephone/FAX
- FA/OA equipment
- Programmable logic controllers

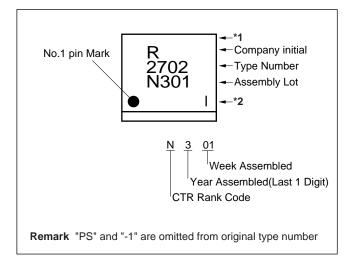
PACKAGE DIMENSIONS (UNIT: mm)



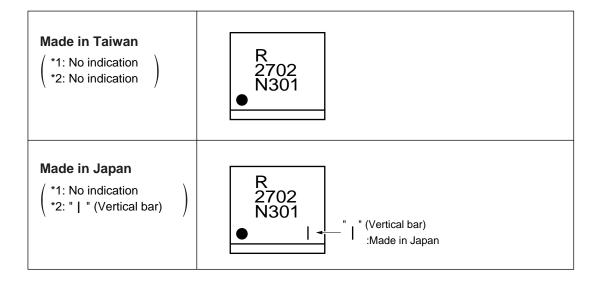
<R> PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	5 mm
Outer Creepage Distance	5 mm
Inner Creepage Distance	2.5 mm
Isolation Thickness	0.3 mm

<R> MARKING EXAMPLE



Note: Bar indication contents of *1 and *2



<R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS2702-1-F3	PS2702-1-F3-A	Pb-Free	Embossed Tape 3 500 pcs/reel	Standard products (UL, BSI, CSA approved)	PS2702-1
PS2702-1-V-F3	PS2702-1-V-F3-A		Embossed Tape 3 500 pcs/reel	DIN EN 60747-5-5 (VDE 0884-5) Approved (Option)	

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit	
Diode	Forward Current (DC)	I _F	50	mA	
	Reverse Voltage	V_R	6.0	V	
	Power Dissipation Derating	⊿P _D /°C	0.8	mW/°C	
	Power Dissipation	P _D	80	mW	
	Peak Forward Current*1	I _{FP} 1		А	
Transistor	Collector to Emitter Voltage	V _{CEO}	40	V	
	Emitter to Collector Voltage	V _{ECO}	6	V	
	Collector Current	Ic	200	mA	
Power Dissipation Derating		⊿P _C /°C	1.5	mW/°C	
	Power Dissipation	Pc	150	mW	
Isolation Voltage *2		BV	3 750	Vr.m.s.	
Operating Ambient Temperature		T _A	-55 to +100	°C	
Storage Temperature		T _{stg}	-55 to +150	°C	

Notes: * 1. PW = 100 μ s, Duty Cycle = 1%

^{*}2. AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.

ELECTRICAL CHARACTERISTICS $(T_A = 25^{\circ}C)$

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V _F	I _F = 5 mA		1.1	1.4	V
	Reverse Current	I _R	V _R = 5 V			5	μА
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz		30		pF
Transistor	Collector to Emitter Dark Current	I _{CEO}	I _F = 0 mA, V _{CE} = 40 V			400	nA
Coupled	Current Transfer Ratio $\left(I_{\text{C}}/I_{\text{F}}\right)^{*1}$	CTR	I _F = 1 mA, V _{CE} = 2 V	200	2 000		%
	Collector Saturation Voltage	V _{CE (sat)}	I _F = 1 mA, I _C = 2 mA			1.0	V
	Isolation Resistance	R _{I-O}	V _{I-O} = 1 kV _{DC}	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.4		pF
	Rise Time *2	t _r	V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω		70		μs
	Fall Time *2	t _f			60		
	Turn-on Time *2	t _{on}			90		
	Turn-off Time *2	t _{off}			60		

<R> <R>

Notes: *1. CTR rank

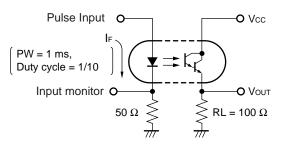
K: 2 000 and larger (%)

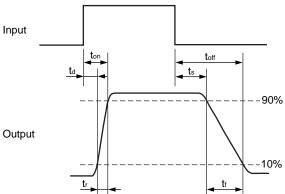
L: 700 to 3 400 (%)

M: 200 to 1 000 (%)

^{*}2. Test circuit for switching time

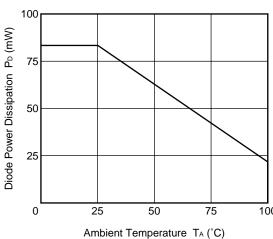
<R>



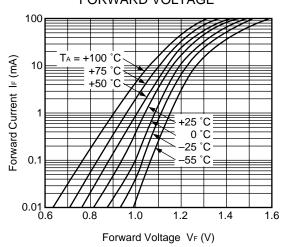


<R> TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

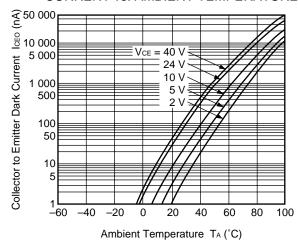




FORWARD CURRENT vs. FORWARD VOLTAGE

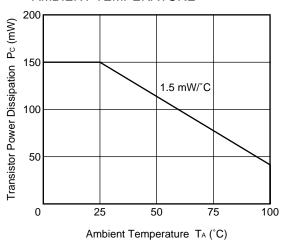


COLLECTOR TO EMITTER DARK **CURRENT vs. AMBIENT**

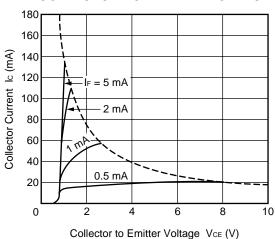


Remark The graphs indicate nominal characteristics.

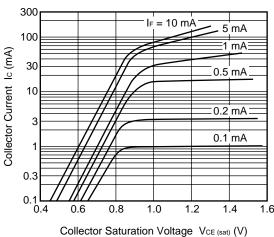
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



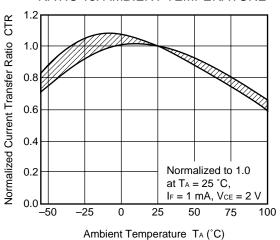
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



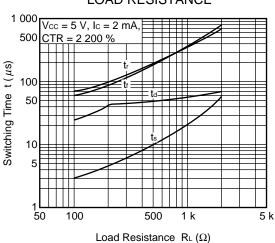
COLLECTOR CURRENT vs. **COLLECTOR SATURATION VOLTAGE**



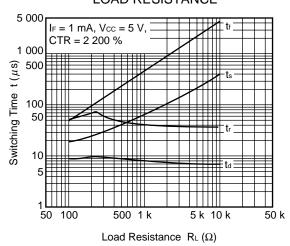
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



SWITCHING TIME vs. LOAD RESISTANCE

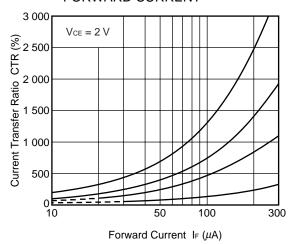


SWITCHING TIME vs. LOAD RESISTANCE

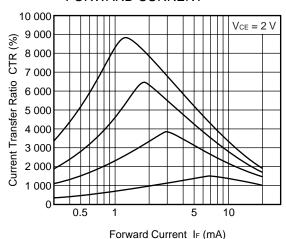


Remark The graphs indicate nominal characteristics.

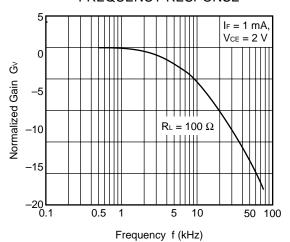
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



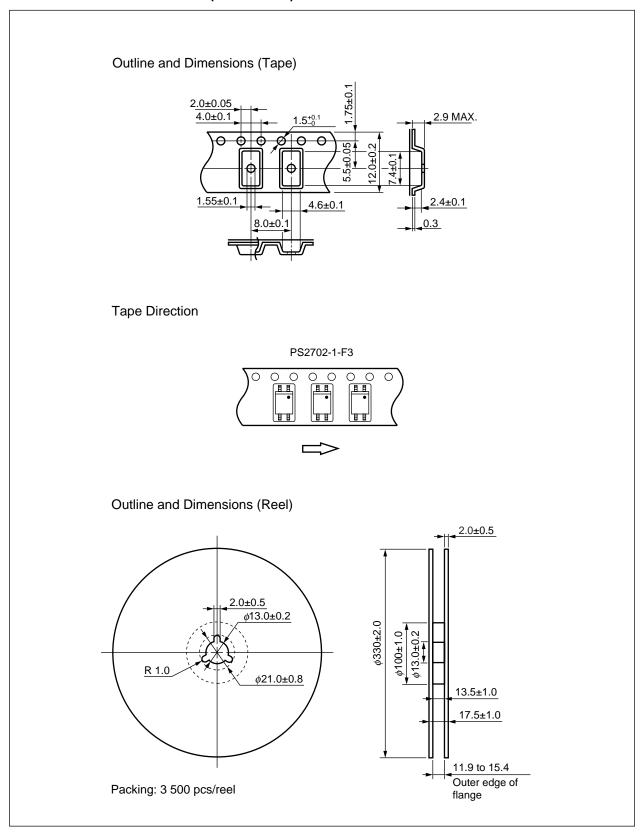
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



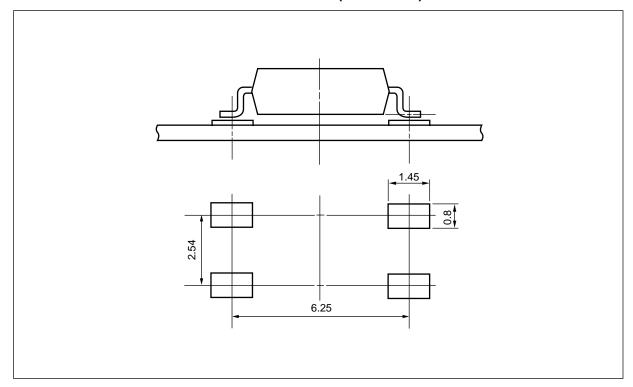
FREQUENCY RESPONSE



<R> TAPING SPECIFICATIONS (UNIT: mm)



<R> RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

NOTES ON HANDLING

- 1. Recommended soldering conditions
 - (1) Infrared reflow soldering
 - Peak reflow temperature
 - Time of peak reflow temperature
 - Time of temperature higher than 220°C
 - Time to preheat temperature from 120 to 180°C
 - · Number of reflows
 - Flux

260°C or below (package surface temperature)

10 seconds or less

60 seconds or less

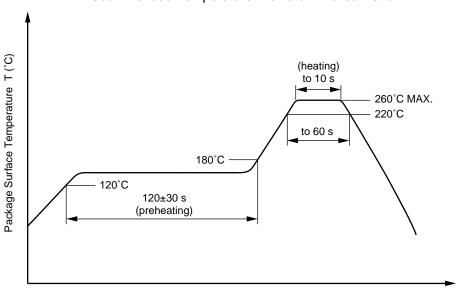
120±30 s

Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is

recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

Temperature

• Time

• Preheating conditions

· Number of times

Flux

260°C or below (molten solder temperature)

10 seconds or less

120°C or below (package surface temperature)

One (Allowed to be dipped in solder including plastic

mold portion.)

Rosin flux containing small amount of chlorine (The flux

with a maximum chlorine content of 0.2 Wt% is

recommended.)

(3) Soldering by Soldering Iron

• Peak Temperature (lead part temperature)

• Time (each pins)

Flux

350°C or below

3 seconds or less

Rosin flux containing small amount of chlorine (The flux

with a maximum chlorine content of 0.2 Wt% is

recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collectoremitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.



<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength			
maximum operating isolation voltage	U_IORM	707	V_{peak}
Test voltage (partial discharge test, procedure a for type test and	U_pr	1 131	V_{peak}
random test)			
$U_{pr} = 1.6 \times U_{IORM}, P_d < 5 pC$			
Test voltage (partial discharge test, procedure b for all devices)	U_pr	1 325	V_{peak}
$U_{pr} = 1.875 \times U_{IORM}, P_d < 5 pC$			
Highest permissible overvoltage	U_TR	6 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE 0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303	CTI	175	
Part 11))			
Material group (DIN EN 60664-1 VDE 0110 Part 1)		III a	
Storage temperature range	T _{stg}	−55 to +150	°C
Operating temperature range	T _A	-55 to +100	°C
Isolation resistance, minimum value			
$V_{IO} = 500 \text{ V dc at T}_{A} = 25^{\circ}\text{C}$	Ris MIN.	10 ¹²	Ω
V _{IO} = 500 V dc at T _A MAX. at least 100°C	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see			
thermal derating curve)			
Package temperature	Tsi	150	°C
Current (input current I _F , Psi = 0)	Isi	300	mA
Power (output or total power dissipation)	Psi	500	mW
Isolation resistance		9	_
V _{IO} = 500 V dc at T _A = Tsi	Ris MIN.	10 ⁹	Ω

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

PS2702-1 Data Sheet

			Description		
Rev.	Date	Page	Summary		
1.00	Mar 31, 2003	_	This data sheet was released as PN10241EJ01V0DS		
3.00	Jan 29, 2013	Renesas format is applied to this data sheet.			
		p.1	The ordering number and safety standards are revised.		
		p.2	PHOTOCOUPLER CONSTRUCTION is added.		
		p.3	The explanation in MARKING EXAMPLE is revised.		
			One of the captions in MARKING EXAMPLE is revised from Trade Mark to Company initial.		
		p.4	ORDERING INFORMATION is modified with the revision of the safety standards.		
		p.5	Turn-on Time (t _{on}) and Turn-off Time (t _{off}) are added to the table in ELECTRICAL CHARACTERISTICS.		
		p.5	The timing chart is added in the note *2.		
		p.6	The graph of LONG TERM CTR DEGRADATION is deleted from those in		
			TYPICAL CHARACTERISTICS.		
		p.8	PS2702-1-F4 is deleted from Tape Direction image in TAPING		
			SPECIFICATIONS.		
		p.9	RECOMMENDED MOUNT PAD DIMENSIONS is added.		
		p.10	The note about temperature condition of the recommended soldering conditions is deleted.		
		p.12	The format of SPECIFICATION OF VDE MARKS LICENSE DOCUMENT is revised.		
			The value of maximum operating isolation voltage is changed to 707.		
			The value of test voltage (partial discharge test, procedure a for type test and random test) is changed to 1130.		
			The value of test voltage (partial discharge test, procedure b for all devices) is changed to 1325.		
			The value of Current (input current I _F , Psi = 0) is changed to 300.		
			The value of Power (output or total power dissipation) is changed to 500.		

NOTICE

- 1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. California Eastern Laboratories and Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software or information.
- 2. California Eastern Laboratories has used reasonable care in preparing the information included in this document, but California Eastern Laboratories does not warrant that such information is error free. California Eastern Laboratories and Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 3. California Eastern Laboratories and Renesas Electronics do not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of California Eastern Laboratories or Renesas Electronics or others.
- 4. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part. California Eastern Laboratories and Renesas Electronics assume no responsibility for any losses incurred by you or third parties arising from such alteration, modification, copy or otherwise misappropriation of Renesas Electronics product.
- 5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots etc. "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; and safety equipment etc. Renesas Electronics products are neither intended nor authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems, surgical implantations etc.), or may cause serious property damages (nuclear reactor control systems, military equipment etc.). You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application for which it is not intended. California Eastern Laboratories and Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for which the product is not intended by California Eastern Laboratories or Renesas Electronics.
- 6. You should use the Renesas Electronics products described in this document within the range specified by California Eastern Laboratories, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. California Eastern Laboratories shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 7. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or systems manufactured by you.
- 8. Please contact a California Eastern Laboratories sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. California Eastern Laboratories and Renesas Electronics assume no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 9. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You should not use Renesas Electronics products or technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. When exporting the Renesas Electronics products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations.
- 10. It is the responsibility of the buyer or distributor of California Eastern Laboratories, who distributes, disposes of, or otherwise places the Renesas Electronics product with a third party, to notify such third party in advance of the contents and conditions set forth in this document, California Eastern Laboratories and Renesas Electronics assume no responsibility for any losses incurred by you or third parties as a result of unauthorized use of Renesas Electronics products.
- 11. This document may not be reproduced or duplicated in any form, in whole or in part, without prior written consent of California Eastern Laboratories.
- 12. Please contact a California Eastern Laboratories sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- NOTE 1: "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- NOTE 2: "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.
- **NOTE 3:** Products and product information are subject to change without notice.

CEL Headquarters • 4590 Patrick Henry Drive, Santa Clara, CA 95054 • Phone (408) 919-2500 • www.cel.com

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET Output Optocouplers category:

Click to view products by RENESAS manufacturer:

Other Similar products are found below:

TLP3131(F) TLP598GAF CPC2014NTR TLP4026G(F) LTV-817S-B CPC2017NTR TLP152(TPL,E(T PS2505L-4-E3-A TLP3106A(TP,F TLP3107A(F TLP3106A(F TLP4176A(F TLP3149(F TLP3147(F TLP3145(F TLP3146(F TLP3149(TP,F H11AV1XSM CNY17-1-000E CNY17-1-300E CNY17-1S CNY17-2-000E CNY17-2S CNY173SR2VM CNY17-4-000E HCPL-181-06DE HCPL-J312-000E LTV-3120S-TA1 LTV-817-L LTV-817M-D LTV-817S-A TIL111 TIL191 MCT6X MCT6XSM TLP170A(F) TLP170G(F) TLP197GA(F) TLP197G(TP,F) TLP222A-2(LF1,F) TLP291(GR-TP.E(O TLP597A(F) TLP797J(F) 4N35X 4N35XSM MOC213M HMHA2801R2 ILD1XSM ILQ2X IS357A